

MOSFETs Silicon N-Channel MOS (π -MOSVII)

TK30J25D

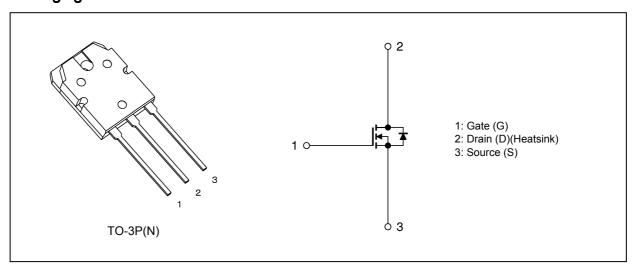
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 0.046 \Omega$ (typ.)
- (2) Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 250 \text{ V)}$
- (3) Enhancement mode: $V_{th} = 1.5 \text{ to } 3.5 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	250	V
Gate-source voltage		V _{GSS}	±20	
Drain current (DC)	(Note 1)	I _D	30	Α
Drain current (pulsed)	(Note 1)	I _{DP}	120	
Power dissipation (T _c =	25°C)	P_{D}	260	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	448	mJ
Avalanche current	(Note 3)	I _{AR}	30	Α
Reverse drain current (DC)	(Note 1)	I _{DR}	30	
Reverse drain current (pulsed)	(Note 1)	I _{DRP}	120	
Channel temperature		T _{ch}	150	°C
Storage temperature		T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production



5. Thermal Characteristics

Characteristics		Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.481	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	50	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 50 V, T_{ch} = 25°C (initial), L = 0.83 mH, R_{G} = 25 $\Omega,\,I_{AR}$ = 30 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 250 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	250	_	_	V
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	1.5	_	3.5	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 15 A	ı	0.046	0.06	Ω

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 100 V, V _{GS} = 0 V, f = 1 MHz	_	4300	_	pF
Reverse transfer capacitance	C _{rss}			30		
Output capacitance	C _{oss}		_	250		
Gate resistance	r _g	V _{DS} = OPEN, f = 1 MHz	1	5.3		Ω
Switching time (rise time)	t _r	See Figure 6.2.1.		85		ns
Switching time (turn-on time)	t _{on}		_	140		
Switching time (fall time)	t _f		_	75	_	
Switching time (turn-off time)	t _{off}		_	520		

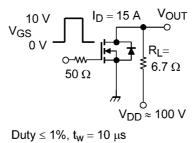


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 200 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	_	100		nC
Gate-source charge 1	Q _{gs1}			16.5		
Gate-drain charge	Q_{gd}			31		

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	V _{DSF}	I _{DR} = 30 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 30 A, V _{GS} = 0 V	_	270	_	ns
Reverse recovery charge	Q _{rr}	-dI _{DR} /dt = 100 A/μs		2.6		μС
Peak reverse recovery current	Irr		_	19	_	Α



7. Marking (Note)

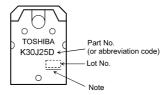


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

Common source

V_{DS} = 10 V

Pulse test

3

₽ 30

Drain current 20

10

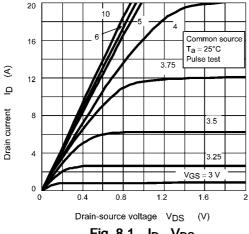
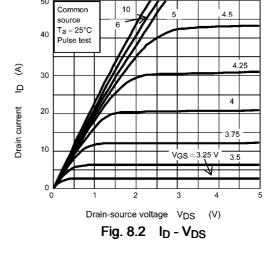
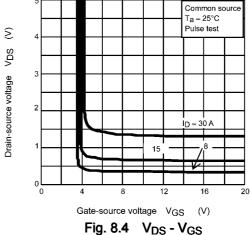


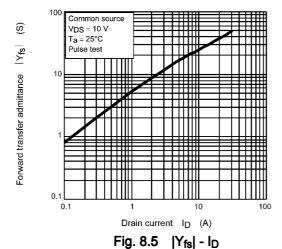
Fig. 8.1 I_D - V_{DS}

-55 °C



 \Im VDS Drain-source voltage





Gate-source voltage VGS

Fig. 8.3 I_D - V_{GS}

Common source Ta = 25°C VGS = 10 V Drain-source on-resistance RDS(ON) (Ω) 0.1 0.01 1000 Drain current ID (A)

Fig. 8.6 R_{DS(ON)} - I_D

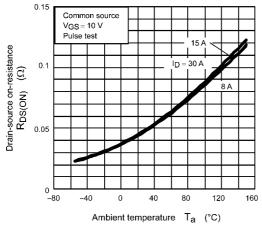
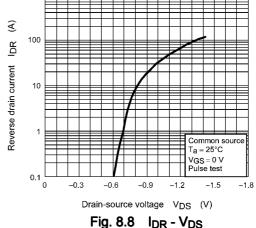


Fig. 8.7 R_{DS(ON)} - T_a



1000

Fig. 8.8 IDR - VDS

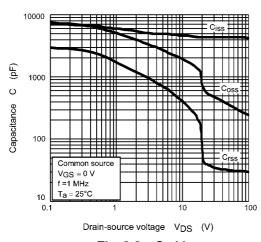


Fig. 8.9 C - V_{DS}

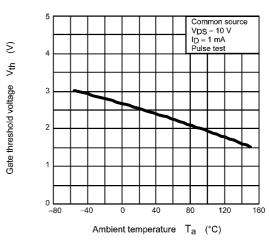


Fig. 8.10 V_{th} - T_a

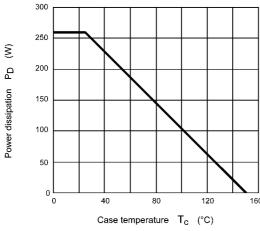


Fig. 8.11 PD - Tc (Guaranteed Maximum)

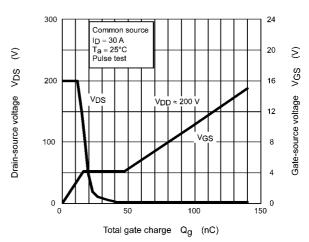


Fig. 8.12 Dynamic Input/Output Characteristics

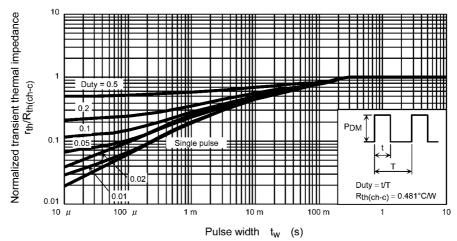


Fig. 8.13 $r_{th}/R_{th(ch-c)} - t_w$ (Guaranteed Maximum)

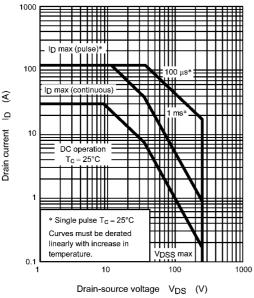


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

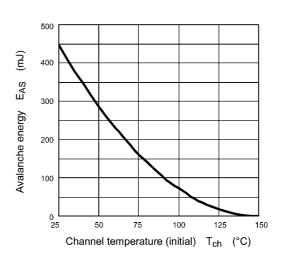


Fig. 8.15 E_{AS} - T_{ch} (Guaranteed Maximum)

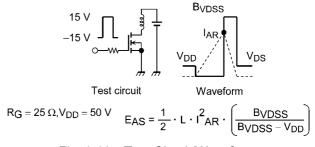


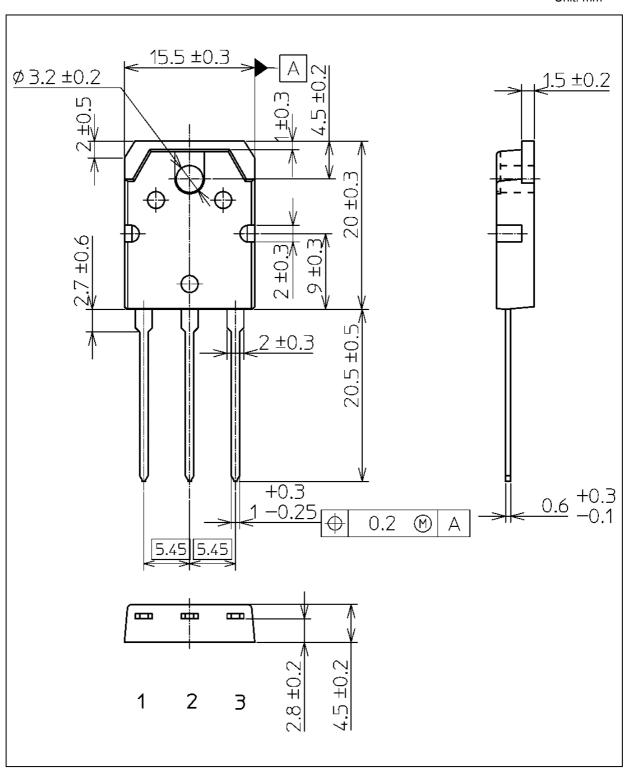
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 4.6 g (typ.)

	Package Name(s)
JEITA: SC-65	
TOSHIBA: 2-16C1S	
Nickname: TO-3P(N)	



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